

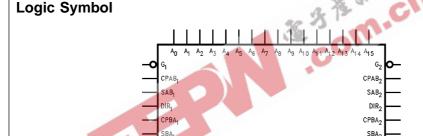
54ACTQ16646 16-Bit Transceiver/Register with TRI-STATE® Outputs

General Description

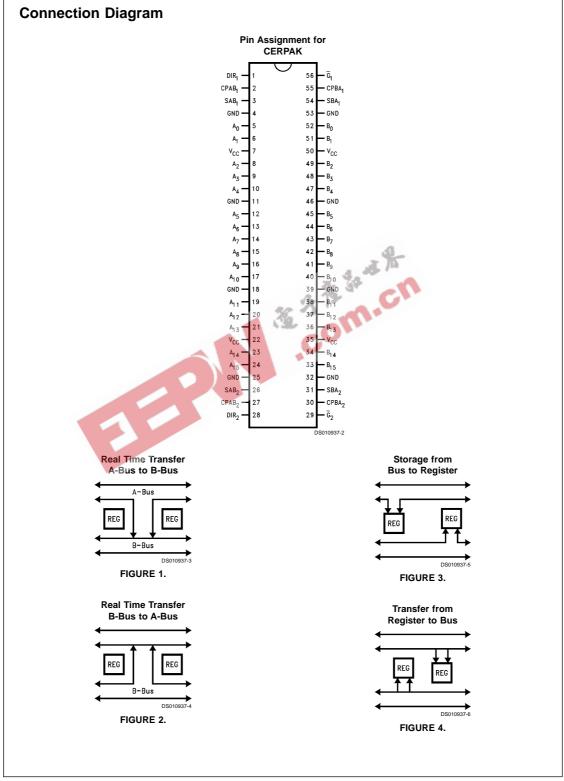
The 'ACTQ16646 contains sixteen non-inverting bidirectional registered bus transceivers providing multiplexed transmission of data directly from the input bus or from the internal storage registers. Each byte has separate control inputs which can be shorted together for full 16-bit operation. The DIR inputs determine the direction of data flow through the device. The CPAB and CPBA inputs load data into the registers on the LOW-to-HIGH transition. The 'ACTQ16646 utilizes NSC Quiet Series technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series® features GTO® output control and undershoot corrector for superior performance.

Features

- Utilizes NSC FACT Quiet Series technology
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Independent registers for A and B buses
- Multiplexed real-time and stored data transfers
- Separate control logic for each byte
- 16-bit version of the 'ACTQ646
- Outputs source/sink 24 mA
- Standard Microcircuit Drawing (SMD) 5962-9581601



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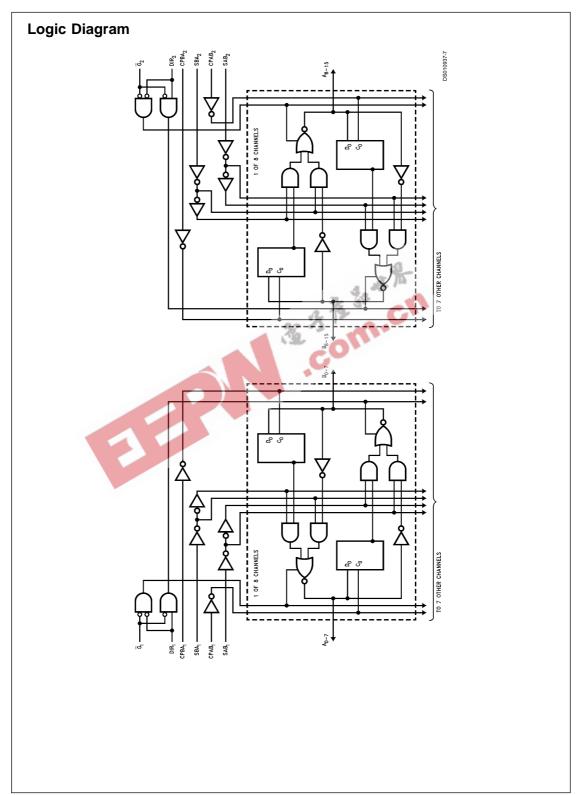
Function Table

Inputs					Data I/O (Note 1)		Output Operation Mode	
G ₁	DIR ₁	CPAB₁	CPBA ₁	SAB ₁	SBA ₁	A ₀₋₇	B ₀₋₇	
Н	Χ	H or L	H or L	Χ	Χ			Isolation
Н	Χ	N	Χ	Χ	X	Input	Input	Clock An Data into A Register
Н	Χ	Χ	N	X	Χ			Clock Bn Data Into B Register
L	Н	Х	Х	L	Х			An to Bn — Real Time (Transparent Mode)
L	Н	N	Χ	L	Χ	Input	Output	Clock An Data to A Register
L	Н	H or L	Χ	Н	Χ			A Register to Bn (Stored Mode)
L	Н	N	X	Н	X			Clock An Data into A Register and Output to Bn
L	L	Х	Х	Х	L			Bn to An — Real Time (Transparent Mode)
L	L	Χ	N	X	L	Output	Input	Clock Bn Data into B Register
L	L	Χ	H or L	X	Н			B Register to An (Stored Mode)
L	L	X	N	X	Н			Clock Bn into B Register and Output to An

H = HIGH Voltage Level X = Immaterial

L = LOW Voltage Level N = LOW-to-HIGH Transition.





Absolute Maximum Ratings (Note 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage (V_{CC}) -0.5V to +7.0VDC Input Diode Current (IIK) $V_1 = -0.5V$ -20 mA $V_I = V_{CC} + 0.5V$ +20 mA DC Output Diode Current (I_{OK}) $V_{\rm O} = -0.5 V$ -20 mA $V_O = V_{CC} + 0.5V$ +20 mA DC Output Voltage (V_O) -0.5V to $V_{\rm CC}$ + 0.5V DC Output Source/Sink Current (Io) ±50 mA DC V_{CC} or Ground Current per Output Pin ±50 mA

CDIP +175°C Storage Temperature -65°C to +150°C

Junction Temperature

Recommended Operating Conditions

Supply Voltage (V_{CC})

 $\begin{tabular}{lll} 'ACTQ & 4.5V to 5.5V \\ Input Voltage (V_I) & 0V to V_{CC} \\ Output Voltage (V_O) & 0V to V_{CC} \\ \end{tabular}$

Operating Temperature (T_A):

Minimum Input Edge Rate (dV/dt)

'ACTQ Devices 125 mV/ns

 $\rm V_{IN}$ from 0.8V to 2.0V $\rm V_{CC}$ @ 4.5V, 5.5V

Note 2: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. National does not recommend operation of FACTTM circuits outside databook specifications.

DC Electrical Characteristics for 'ACTQ Family Devices.

Symbol	Parameter	V _{cc}	54ACTQ	Units	Conditions
		(V)	$T_A = -55^{\circ}C \text{ to } +125^{\circ}C$	G	
			26 0	100	
			Guaranteed Limits		
V _{IH}	Minimum High	4.5	2.0	V	V _{OUT} = 0.1V
	Input Voltage	5.5	2.0		or V _{CC} – 0.1V
V _{IL}	Maximum Low	4.5	0.8	V	V _{OUT} = 0.1V
	Input Voltage	5.5	0.8		or V _{CC} – 0.1V
V _{OH}	Minimum High	4.5	4.4	V	I _{OUT} = -50 μA
	Output Voltage	5.5	5.4		
					V _{IN} = V _{IL} or V _{IH}
		4.5	3.70	V	$I_{OH} = -24 \text{ mA}$
		5.5	4.70		$I_{OH} = -24 \text{ mA}$
V _{OL}	Maximum Low	4.5	0.1	V	I _{OUT} = 50 μA
	Output Voltage	5.5	0.1		
					$V_{IN} = V_{IL} \text{ or } V_{IH}$
		4.5	0.50	V	I _{OL} = 24 mA
		5.5	0.50		I _{OL} = 24 mA
l _{ozt}	Maximum I/O	5.5	±10.0	μA	$V_{IN} = V_{IL}, V_{IH}$
	Leakage Current				$V_O = V_{CC}$, GND
I _{IN}	Maximum Input	5.5	±1.0	μA	V _I = V _{CC} , GND
	Leakage Current				
I _{CCT}	Maximum I _{CC} /Input	5.5	1.6	mA	$V_I = V_{CC} - 2.1V$
I _{cc}	Max Quiescent	5.5	160.0	μA	$V_{IN} = V_{CC}$ or GND
	Supply Current				
I _{OLD}	Minimum Dynamic	5.5	50	mA	V _{OLD} = 1.65V Max
I _{OHD}	Output Current (Note 4)		50	mA	V _{OHD} = 3.85V Min
V _{OLP}	Quick Output	5.0	1.1	V	
	Maximum Dynamic V _{OL}				(Notes 5, 6)
V _{OLV}	Quick Output	5.0	-0.8	V	
	Minimum Dynamic V _{OL}				(Notes 5, 6)

Note 3: All outputs loaded; thresholds associated with output under test.

Note 4: Maximum test duration 2.0 ms; one output loaded at a time.

Note 5: Maximum number of outputs that can switch simultaneously is n. (n - 1) outputs are switched LOW and one output held LOW.

5

DC Electrical Characteristics for 'ACTQ Family Devices (Continued)

Note 6: Maximum number of outputs that can switch simultaneously is n. (n - 1) outputs are switched HIGH and one output held HIGH.

AC Electrical Characteristics

Symbol	Parameter	V _{cc}	54AC	Units	
		(V)	T _A = -55°C		
		(Note 7)	C _L = 5		
			Min	Max	
t _{PHL}	Propagation Delay	5.0	2.9	10.2	ns
t _{PLH}	Clock to Bus		3.2	10.2	
t _{PHL}	Propagation Delay	5.0	3.6	11.5	ns
t _{PLH}	Bus to Bus		3.3	10.8	
t _{PHL}	Propagation Delay	5.0	3.1	11.3	ns
t _{PLH}	Select to Bus		3.2	11.5	
	(w/An or Bn				
	HIGH or LOW)		.0		
t _{PZL}	Enable Time	5.0	3.8	12.9	ns
t _{PZH}	G to An/Bn		3. 3	11.9	
t _{PLZ}	Disable Time	5.0	2.3	9.8	ns
t_{PHZ}	G to An/Bn		2.6	9.5	
t _{PZL}	Enable Time	5.0	4.3	14.0	ns
t _{PZH}	DIR to An/Bn		3.7	12.8	
t _{PLZ}	Disable Time	5.0	2.0	10.8	ns
t _{PHZ}	DIR to An/Bn		2.5	11.0	

Note 7: Voltage Range 5.0 is 5.0V ±0.5V.

AC Operating Requirements

Symbol	Parameter	V _{cc}	54ACTQ	Units
		(V)	T _A = -55°C to +125°C	
		(Note 8)	C _L = 50 pF	
			Guaranteed Minimum	
t _S	Setup Time, H or L	5.0	3.0	ns
	Bus to Clock			
t _H	Hold Time, H or L	5.0	1.5	ns
	Bus to Clock			
t _w	Clock Pulse Width	5.0	4.0	ns
	H or L			

Note 8: Voltage Range 5.0 is 5.0V ±0.5V.

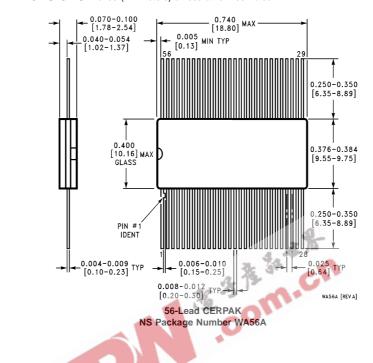
Capacitance

Symbol	Parameter	Тур	Units	Conditions
C _{IN}	Input Capacitance	4.5	pF	V _{CC} = 5.0V
C _{PD}	Power Dissipation	95	pF	V _{CC} = 5.0V
	Capacitance			

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Physical Dimensions inches (millimeters) unless otherwise noted



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